

Vishay Siliconix

P-Channel 30 V (D-S) 175 °C MOSFET

DESCRIPTION

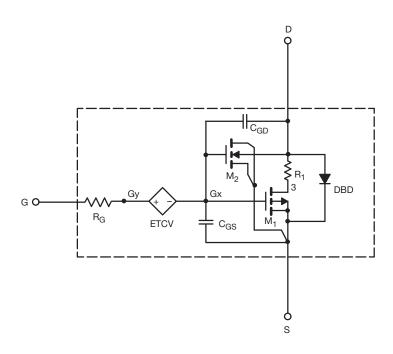
The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the - $55\,^{\circ}$ C to 125 $^{\circ}$ C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- P-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

SUBCIRCUIT MODEL SCHEMATIC



Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

SPICE Device Model SQ4425EY

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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = - 250 μA	2	-	V
Drain-Source On-State Resistance ^a	D	V _{GS} = - 10 V, I _D = - 13 A	0.006	0.009	Ω
	R _{DS(on)}	V _{GS} = - 4.5 V, I _D = - 10 A	0.015	0.015	
Forward Transconductancea	9 _{fs}	V _{DS} = - 15 V, I _D = - 13 A	34	35	S
Diode Forward Voltage	V _{SD}	I _S = - 10 A	- 0.82	- 0.82	V
Dynamic ^b					
Input Capacitance	C _{iss}	V _{DS} = - 25 V, V _{GS} = 0 V, f = 1 MHz	2910	2900	pF
Output Capacitance	C _{oss}		516	527	
Reverse Transfer Capacitance	C _{rss}		386	418	
Total Gate Charge	Qg	V _{DS} = - 15 V, V _{GS} = - 4.5 V, I _D = - 11 A	32	33.6	nC
Gate-Source Charge	Q _{gs}		8.6	8.6	
Gate-Drain Charge	Q_{gd}		15.2	15.2	

Notes

- a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

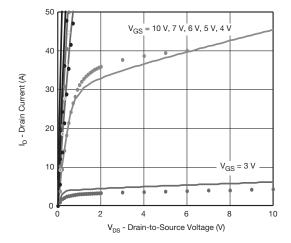
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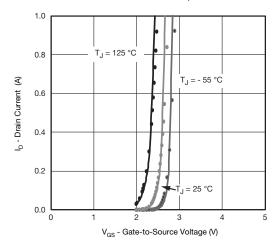


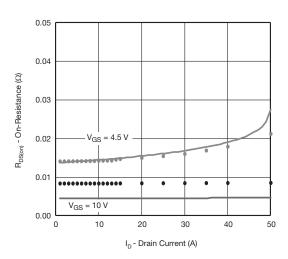
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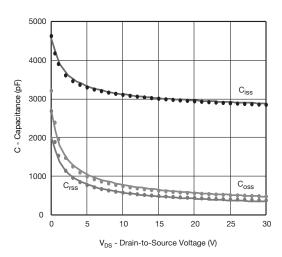
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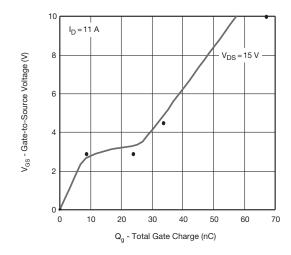
COMPARISON OF MODEL WITH MEASURED DATA ($T_J = 25~^{\circ}C$, unless otherwise noted)

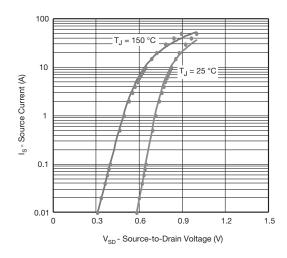












Note

• Dots and squares represent measured data.



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